

产品规格书

批 准	审 核	校 核	编 制
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2018. 03. 02	2018. 03. 02	2018. 03. 02	2018. 03. 02

规格书更改履历:

序号	更改内容	履历号	更改时间	责任人
1	新规制定	000	2018. 03. 02	郑羿



Small Signal Fast Switching Diode

General Description

Dual general-purpose switching diodes, fabricated in planar technology, and packaged in small SOT-23 surface mounted device (SMD) packages.

Features and Benefits

Silicon epitaxial planar diode High switching speed: trr≤4ns

Low forward drop voltage and low leakage current



SOT-23

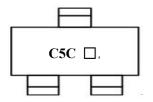
Applications

Ultra high speed switching application

Ordering Information

Part Number	Marking Code	Package	Packaging
KDS7000C	C5C 🔲,	SOT-23	Tape & Reel

Marking Information



C5C= Specific Device Code

☐ = Year & Week Code Marking

• = DaLian

Pinning Information

Pin	Description	Simplified Outline	Graphic Symbol
1	Anode (Diode 1)	<u>□</u> 3	
2	Cathode (Diode 2)		💉 🦎
3	Cathode (Diode 1), Anode (Diode 2)	1 1 12	

Absolute Maximum Ratings (Tamb=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Maximum repetitive peak reverse voltage	V _{RM}	85	V
Continuous reverse voltage	VR	80	V
Maximum average forward rectified current	lo	100	mA
Forward current (DC)	lF	100	mA
Maximum repetitive peak forward current	Iғм	300	mA
Non-repetitive peak forward surge current(t=10ms)	IFSM	2	Α
Power dissipation	Po	150	mW

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Thermal Characteristics (Tamb=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Thermal resistance, junction to ambient	Rth(j-a)	830	°CW
Operating junction temperature	Tj	150	$^{\circ}\!\mathbb{C}$
Storage temperature range	Tstg	-50~150	$^{\circ}\! \mathbb{C}$

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Electrical Characteristics (Tamb=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit.
	V _{F(1)}	I⊧=1mA	-	0.6	-	٧
Forward voltage	V _{F(2)}	I=10mA	-	0.7	-	٧
	VF(3)	I=100mA	-	0.9	1.2	٧
Reverse leakage current	lr	V _R =80V	-	ı	0.5	μд
Total capacitance	Ст	V _R =0V, f=1 MHz	-	2.2	4.0	pF
Reverse recovery time	trr	I _F =10mA (Fig. 5)	-	1.6	4.0	ns

²⁾ Pulse test: $t_P \le 380 \mu s$, Duty $cycle \le 2\%$

³⁾ Pulse test: tp≤5 ms, Duty cycle≤2%

Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics

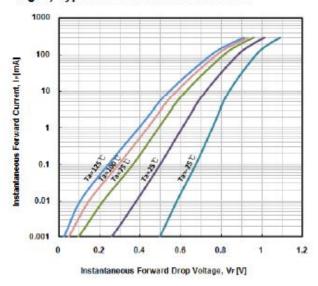


Fig. 2) Typical Reverse Characteristics

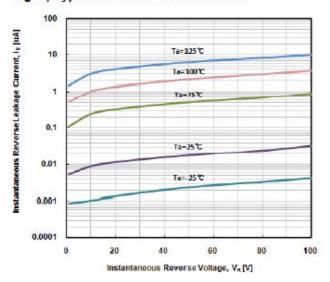


Fig. 3) Typical Total Capacitance Characteristics

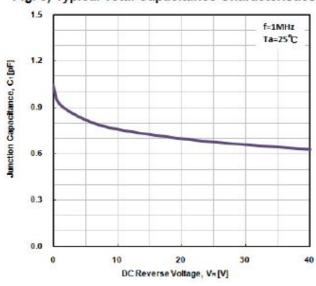


Fig. 4) Reverse Recovery Time vs. Forward Current

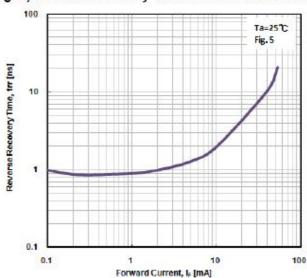
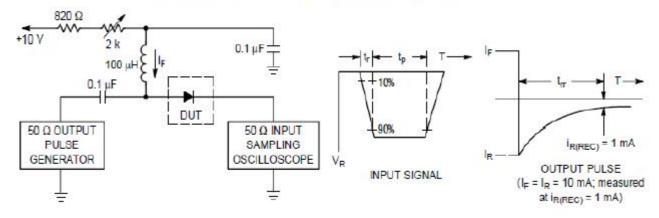
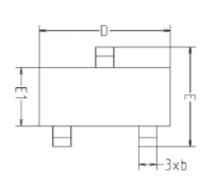
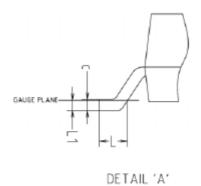


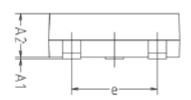
Fig. 5) Reverse recovery time equivalent test circuit

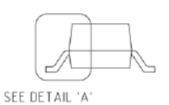


Package Outline Dimensions



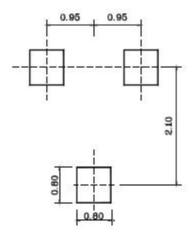






SYMBOL	MILLIMETERS			NOTE
3111000	MINIMUM	NOMINAL	MUMIXAM	14012
Α1	0.00	-	0.10	
A2	0.82	-	1.02	
Ь	0.39	0.42	0.45	
C	0.09	0.12	0.15	
D	2.80	2.90	3.00	
E	2.20	2.40	2.60	
E1	1.20	1.30	1.40	
e	1.90BSC			
L	0.20	-	-	
L1		0.12BSC		

* Recommend PCB solder land (Unit: mm)



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